

Title (en)  
ASYMMETRIC GROUP 8 (VIII) METALLOCENE COMPOUNDS

Title (de)  
ASYMMETRISCHE GRUPPE-8-(VIII-)METALLOCENVERBINDUNGEN

Title (fr)  
COMPOSES METALLOCENE ASYMETRIQUES DU GROUPE 8 (VIII)

Publication  
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Application  
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Abstract (en)  
[origin: WO2004042354A2] A method for producing Group 8 (VIII) metallocene or metallocene-like compounds employs a compound that includes a Cp' anion, such as found, together with a counterion, in a cyclopentadienide or cyclopentadienide-like salt. In one embodiment, the method includes reacting a metal salt, a (Cp) compound, such as a substituted or unsubstituted cyclopentadiene or indene, and a ligand (L) to form an intermediate compound and reacting the intermediate compound with a Cp' compound, eg., a cyclopentadienide or cyclopentadienide-like salt, where the metal salt can be is a ruthenium, an osmium or an iron halide or nitrate and L is an electron pair donor. Unsubstituted, mono-substituted as well as symmetrically or asymmetrically di- or multi-substituted metallocenes or metallocene-like compounds can be produced. In another embodiment, unsubstituted or symmetrically substituted metallocenes are formed by reacting MX<sub>2</sub>(PPh<sub>3</sub>)<sub>m</sub> with a Cp' compound, where m = 3 or 4. The method can be used to form precursors for chemical vapor deposition of thin films.

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Citation (search report)

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